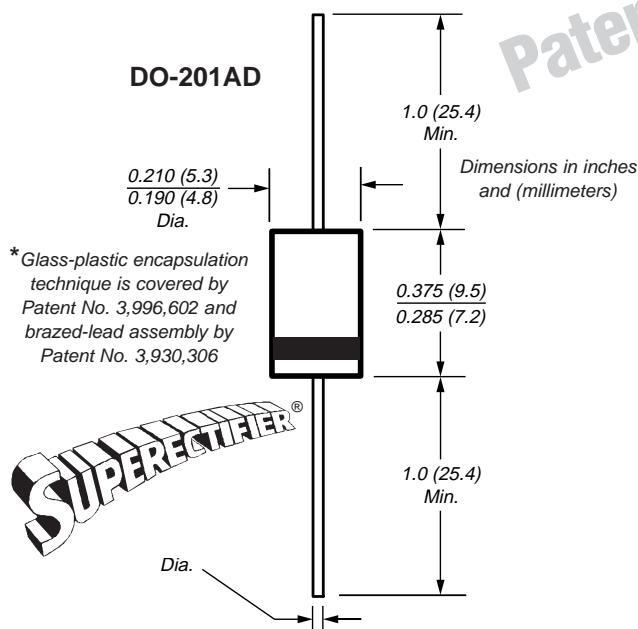


Glass Passivated Junction Plastic Rectifiers

Reverse Voltage

50 to 1000V

Forward Current 3.0A



Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- 3.0 Ampere operation at TA=55°C with no thermal runaway
- Typical IR less than 0.1µA
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-201AD, molded plastic over glass body

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.04oz., 1.12g

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	GP30A	GP30B	GP30D	GP30G	GP30J	GP30K	GP30M	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA = 55°C	I _{F(AV)}					3.0			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}				125				A
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length at TA = 55°C	I _{R(AV)}				100				µA
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}				20				°C/W
Operating junction and storage temperature range	T _J , T _{STG}				-65 to +175				°C

Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	GP30A	GP30B	GP30D	GP30G	GP30J	GP30K	GP30M	Unit
Maximum instantaneous forward voltage at 3.0A	V _F	1.2			1.1				V
Maximum reverse current TA = 25°C at rated DC blocking voltage TA = 125°C	I _R				5.0				µA
Maximum reverse recovery time I _F = 0.5A, I _R = 1.0V, I _{rr} = 0.25A	t _{rr}				5.0				µs
Typical junction capacitance at 4.0V, 1MHz	C _J				40				pF

Note: (1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted

GP30A thru GP30M

Vishay Semiconductors
formerly General Semiconductor



Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig 1 – Forward Current Derating Curve

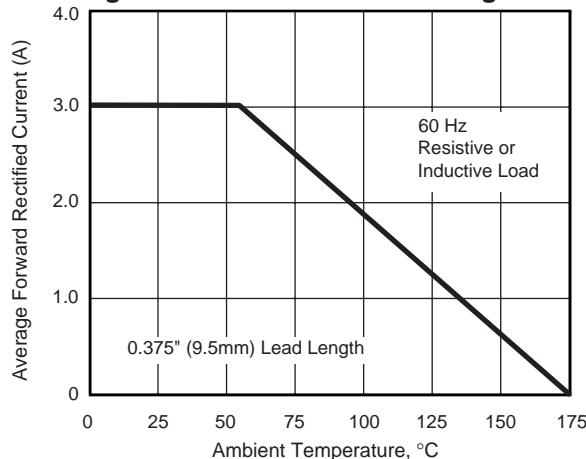


Fig 2 – Maximum Non-repetitive Peak Forward Surge Current

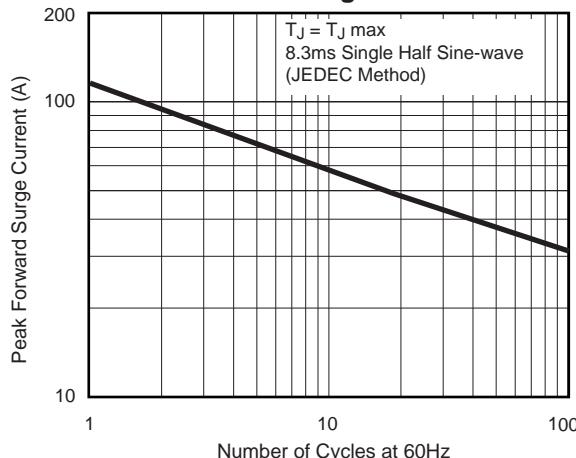


Fig 3 – Typical Instantaneous Forward Characteristics

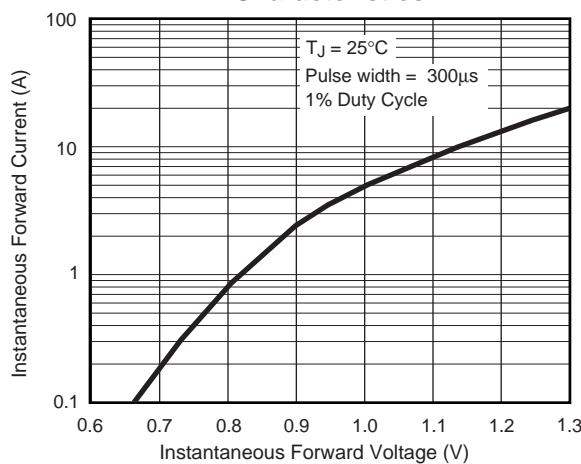


Fig 4 – Typical Reverse Characteristics

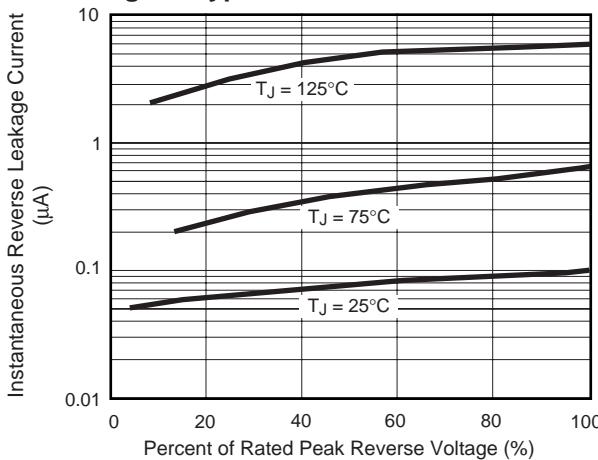
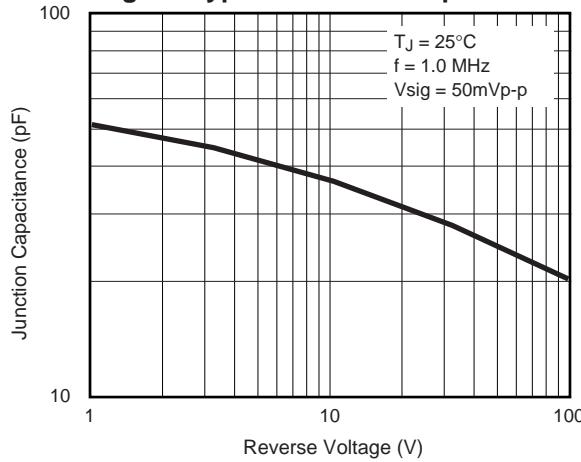


Fig 5 – Typical Junction Capacitance



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